# **SKET 800**

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SEMIPACK<sup>®</sup> 6

**Thyristor Modules** 

#### **SKET 800**

Target Data

### Features

- Precious metal pressure contacts for high reliability
- Thyristor with amplifying gate

### **Typical Applications**

- DC motor control (e. g. for machine tools)
- Temperature control (e. g. for ovens, chemical processes)
- Softstart application

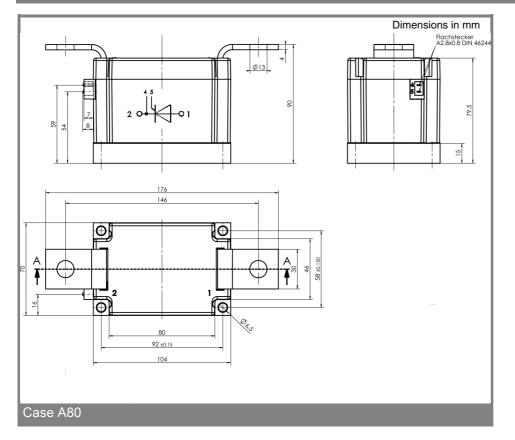
V <sub>RSM</sub>	V <sub>RRM</sub> , V <sub>DRM</sub>	I <sub>TRMS</sub> = 1500 A (maximum value for continuous operation)	
V	V	I <sub>TAV</sub> = 805 A (sin. 180; T <sub>c</sub> = 85 °C)	
1500	1400	SKET 800/14E H4	
1900	1800	SKET 800/18E H4	

Symbol	Conditions	Values	Units
I <sub>TAV</sub>	sin. 180; T <sub>c</sub> = 85 (100) °C	805 (580 )	А
I <sub>TSM</sub>	T <sub>vi</sub> = 25 °C; 10 ms	40000	А
	T <sub>vi</sub> = 130 °C; 10 ms	35000	A
i²t	T <sub>vj</sub> = 25 °C; 8,3 10 ms	8000000	A²s
	T <sub>vj</sub> = 130 °C; 8,3 10 ms	6125000	A²s
V <sub>T</sub>	T <sub>vi</sub> = 25 °C; I <sub>T</sub> = 3000 A	max. 1,55	V
V <sub>T(TO)</sub>	T <sub>vi</sub> = 130 °C	max. 0,98	V
r <sub>T</sub>	T <sub>vi</sub> = 130 °C	max. 0,175	mΩ
I <sub>DD</sub> ; I <sub>RD</sub>	$T_{vj} = 130 \text{ °C}; V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$	max. 150	mA
t <sub>gd</sub>	T <sub>vi</sub> = 25 °C; I <sub>G</sub> = 1 A; di <sub>G</sub> /dt = 1 A/μs	1	μs
t <sub>gr</sub>	$V_{\rm D} = 0,67 * V_{\rm DRM}$	2	μs
(di/dt) <sub>cr</sub>	T <sub>vi</sub> = 130 °C	max. 200	A/µs
(dv/dt) <sub>cr</sub>	T <sub>vi</sub> = 130 °C	max. 1000	V/µs
t <sub>q</sub>	T <sub>vi</sub> = 130 °C	200	μs
Ι <sub>Η</sub>	T <sub>vj</sub> = 25 °C; typ. / max.	1000 / 2000	mA
I <sub>L</sub>	$T_{vj} = 25 \text{ °C}; R_G = 33 \Omega; typ. / max.$	1500 / 2500	mA
V <sub>GT</sub>	T <sub>vi</sub> = 25 °C; d.c.	min. 3	V
I <sub>GT</sub>	$T_{vi} = 25 \text{ °C; d.c.}$	min. 300	mA
V <sub>GD</sub>	T <sub>vi</sub> = 130 °C; d.c.	max. 0,25	V
I <sub>GD</sub>	$T_{vj} = 130 \ ^{\circ}C; \ d.c.$	max. 10	mA
R <sub>th(j-c)</sub>	cont.	0,0405	K/W
R <sub>th(j-c)</sub>	sin. 180	0,042	K/W
R <sub>th(j-c)</sub>	rec. 120	0,043	K/W
R <sub>th(c-s)</sub>		0,01	K/W
T <sub>vj</sub>		- 40 + 130	°C
T <sub>stg</sub>		- 40 + 125	°C
V <sub>isol</sub>	a. c. 50 Hz; r.m.s.; 1s / 1 min.	4800 / 4000	٧~
M <sub>s</sub>	to heatsink	6 ± 15 %	Nm
Mt	to terminal	18 ± 15 %	Nm
а		5 * 9,81	m/s²
m	approx.	2150	g
Case		A80	

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